



SHEET 1 OF 1

Form PTO 1449 (Modified)		U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE		ATTY DOCKET NO. 240128US2S	SERIAL NO. 10/615,181		
LIST OF REFERENCES CITED BY APPLICANT				APPLICANT Daisaburo TAKASHIMA			
				FILING DATE July 9, 2003	GROUP		
<b>U.S. PATENT DOCUMENTS</b>							
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE
	AA						
	AB						
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	AN						
<b>FOREIGN PATENT DOCUMENTS</b>							
		DOCUMENT NUMBER	DATE	COUNTRY	TRANSLATION		
					YES	NO	
	AO						
	AP						
	AQ						
	AR						
	AS						
	AT						
	AU						
	AV						
<b>OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, etc.)</b>							
691	AW	D. TAKASHIMA, et al., IEEE Journal of Solid-State Circuits, vol. 33, no. 5, pages 787-792, "HIGH-DENSITY CHAIN FERROELECTRIC RANDOM ACCESS MEMORY (CHAIN FRAM)", May 1998					
691	AX	S. ONISHI, et al., IEDM, pages 843-846, "A HALF-MICRON FERROELECTRIC MEMORY CELL TECHNOLOGY WITH STACKED CAPACITOR STRUCTURE", 1994					
	AY						
	AZ					<input type="checkbox"/> Additional References sheet(s) attached	
Examiner <i>691</i>				Date Considered <i>9-25-04</i>			
*Examiner: Initial if reference is considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.							